MC14097B
See Page 150

MC14099B
MC14599B

8-Bit Addressable Latches

The MC14099B and MC14599B are 8–bit addressable latches. Data is entered in serial form when the appropriate latch is addressed (via address pins A0, A1, A2) and write disable is in the low state. Chip enable must be high for writing into MC14599B. For the MC14599B the data pin is a bidirectional data port and for the MC14099B the input is a unidirectional write only port. The Write/$\overline{\text{Read}}$ line controls this port in the MC14599B.

The data is presented in parallel at the output of the eight latches independently of the state of Write Disable, Write/$\overline{\text{Read}}$ or Chip Enable.

A Master Reset capability is available on both parts.

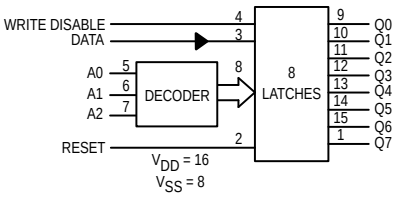
- Serial Data Input
- Parallel Output
- Master Reset
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low–power TTL Loads or One Low–Power Schottky TTL Load over the Rated Temperature Range
- MC14099B pin for pin compatible with CD4099B

MAXIMUM RATINGS* (Voltages Referenced to V_{SS})

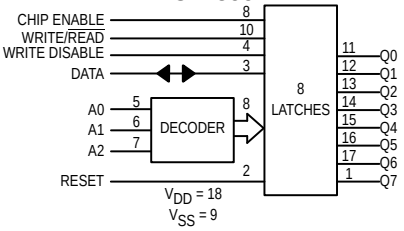
Symbol	Parameter	Value	Unit
V_{DD}	DC Supply Voltage	– 0.5 to + 18.0	V
V_{in}, V_{out}	Input or Output Voltage (DC or Transient)	– 0.5 to V_{DD} + 0.5	V
I_{in}, I_{out}	Input or Output Current (DC or Transient), per Pin	± 10	mA
P_D	Power Dissipation, per Package†	500	mW
T_{stg}	Storage Temperature	– 65 to + 150	°C
T_L	Lead Temperature (8–Second Soldering)	260	°C

* Maximum Ratings are those values beyond which damage to the device may occur.
†Temperature Derating:
Plastic “P and D/DW” Packages: – 7.0 mW/°C From 65°C To 125°C
Ceramic “L” Packages: – 12 mW/°C From 100°C To 125°C

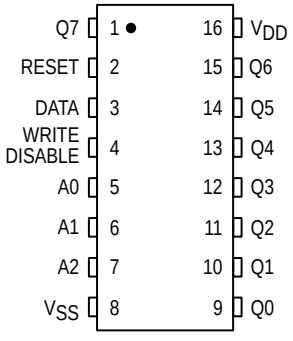
MC14099B



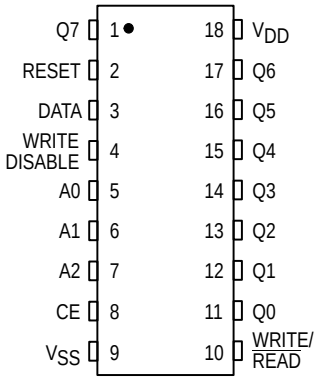
MC14599B

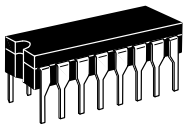


PIN ASSIGNMENT

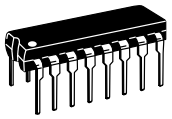


PIN ASSIGNMENT

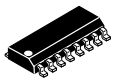




L SUFFIX
CERAMIC
CASE 620



P SUFFIX
PLASTIC
CASE 648

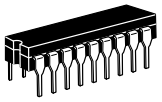


DW SUFFIX
SOIC
CASE 751G

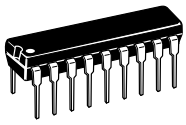
ORDERING INFORMATION

MC14099BCP	Plastic
MC14099BCL	Ceramic
MC14099BDW	SOIC

T_A = – 55° to 125°C for all packages.



L SUFFIX
CERAMIC
CASE 726



P SUFFIX
PLASTIC
CASE 707

ORDERING INFORMATION

MC14599BCP	Plastic
MC14599BCL	Ceramic

T_A = – 55° to 125°C for all packages.

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \le (V_{in}$ or $V_{out}) \le V_{DD}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.

REV 0
1/94

ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

Characteristic	Symbol	V_{DD} Vdc	– 55°C		25°C			125°C		Unit
			Min	Max	Min	Typ #	Max	Min	Max	
Output Voltage “0” Level V_{in} = V_{DD} or 0	V_{OL}	5.0 10 15	— — —	0.05 0.05 0.05	— — —	0 0 0	0.05 0.05 0.05	— — —	0.05 0.05 0.05	Vdc
“1” Level V_{in} = 0 or V_{DD}	V_{OH}	5.0 10 15	4.95 9.95 14.95	— — —	4.95 9.95 14.95	5.0 10 15	— — —	4.95 9.95 14.95	— — —	Vdc
Input Voltage “0” Level (V_O = 4.5 or 0.5 Vdc) (V_O = 9.0 or 1.0 Vdc) (V_O = 13.5 or 1.5 Vdc)	V_{IL}	 5.0 10 15	 — — —	 1.5 3.0 4.0	 — — —	 2.25 4.50 6.75	 1.5 3.0 4.0	 — — —	 1.5 3.0 4.0	Vdc
“1” Level (V_O = 0.5 or 4.5 Vdc) (V_O = 1.0 or 9.0 Vdc) (V_O = 1.5 or 13.5 Vdc)	V_{IH}	 5.0 10 15	 3.5 7.0 11	 — — —	 3.5 7.0 11	 2.75 5.50 8.25	 — — —	 3.5 7.0 11	 — — —	Vdc
Output Drive Current (V_{OH} = 2.5 Vdc) Source (V_{OH} = 4.6 Vdc) (V_{OH} = 9.5 Vdc) (V_{OH} = 13.5 Vdc)	I_{OH}	 5.0 5.0 10 15	 – 3.0 – 0.64 – 1.6 – 4.2	 — — — —	 – 2.4 – 0.51 – 1.3 – 3.4	 – 4.2 – 0.88 – 2.25 – 8.8	 — — — —	 – 1.7 – 0.36 – 0.9 – 2.4	 — — — —	mAdc
(V_{OL} = 0.4 Vdc) Sink (V_{OL} = 0.5 Vdc) (V_{OL} = 1.5 Vdc)	I_{OL}	5.0 10 15	0.64 1.6 4.2	— — —	0.51 1.3 3.4	0.88 2.25 8.8	— — —	0.36 0.9 2.4	— — —	mAdc
Input Current	I_{in}	15	—	± 0.1	—	±0.00001	± 0.1	—	± 1.0	µAdc
Input Capacitance (V_{in} = 0)	C_{in}	—	—	—	—	5.0	7.5	—	—	pF
Input Capacitance MC14599B — Data (pin 3) (V_{in} = 0)	C_{in}	—	—	—	—	15	22.5	—	—	pF
Quiescent Current (Per Package)	I_{DD}	5.0 10 15	— — —	5.0 10 20	— — —	0.005 0.010 0.015	5.0 10 20	— — —	150 300 600	µAdc
Total Supply Current**† (Dynamic plus Quiescent, Per Package) (C_L = 50 pF on all outputs, all buffers switching)	I_T	5.0 10 15	I_T = (1.5 µA/kHz) f + I_{DD} I_T = (3.0 µA/kHz) f + I_{DD} I_T = (4.5 µA/kHz) f + I_{DD}							µAdc

#Data labelled “Typ” is not to be used for design purposes but is intended as an indication of the IC’s potential performance.

**The formulas given are for the typical characteristics only at 25°C.

†To calculate total supply current at loads other than 50 pF:

$$I_T(C_L) = I_T(50\ pF) + (C_L - 50)\ Vfk$$

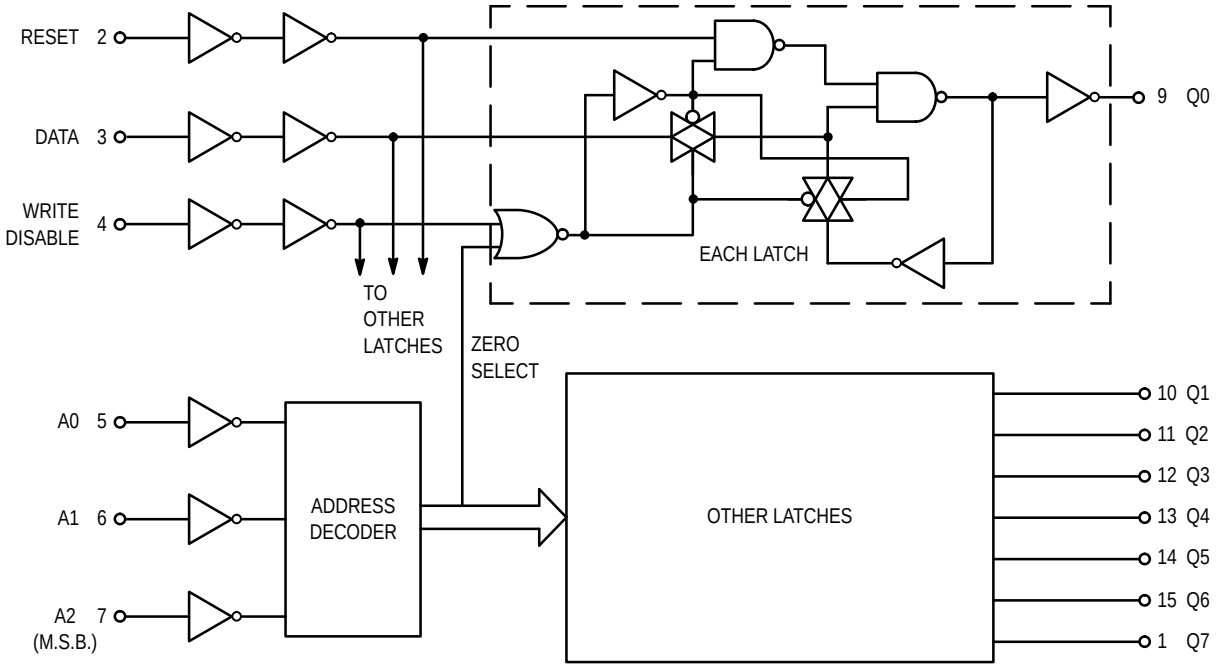
where: I_T is in µA (per package), C_L in pF, V = (V_{DD} – V_{SS}) in volts, f in kHz is input frequency, and k = 0.004.

SWITCHING CHARACTERISTICS* (C_L = 50 pF, T_A = 25°C)

Characteristic	Symbol	V_{DD} Vdc	Min	Typ #	Max	Unit
Output Rise and Fall Time	t_{TLH},					ns
t_{TLH}, t_{THL} = (1.35 ns/pF) C_L + 32 ns	t_{THL}	5.0	—	100	200	
t_{TLH}, t_{THL} = (0.6 ns/pF) C_L + 20 ns		10	—	50	100	
t_{TLH}, t_{THL} = (0.4 ns/pF) C_L + 20 ns		15	—	40	80	
Propagation Delay Time	t_{PHL},					ns
Data to Output Q	t_{PLH}	5.0	—	200	400	
		10	—	75	150	
		15	—	50	100	
Write Disable to Output Q		5.0	—	200	400	ns
		10	—	80	160	
		15	—	60	120	
Reset to Output Q		5.0	—	175	350	ns
		10	—	80	160	
		15	—	65	130	
CE to Output Q (MC14599B only)		5.0	—	225	450	ns
		10	—	100	200	
		15	—	75	150	
Propagation Delay Time, MC14599B only	t_{PHL},					ns
Chip Enable, Write/$\overline{\text{Read}}$ to Data	t_{PLH}	5.0	—	200	400	
		10	—	80	160	
		15	—	65	130	
Address to Data		5.0	—	200	400	ns
		10	—	90	180	
		15	—	75	150	
Pulse Widths	$t_{w(H)}$					ns
Reset	$t_{w(L)}$	5.0	150	75	—	
		10	75	40	—	
		15	50	25	—	
Write Disable		5.0	320	160	—	ns
		10	160	80	—	
		15	120	60	—	
Set Up Time	t_{su}					ns
Data to Write Disable		5.0	100	50	—	
		10	50	25	—	
		15	35	20	—	
Hold Time	t_h					ns
Write Disable to Data		5.0	150	75	—	
		10	75	40	—	
		15	50	25	—	
Set Up Time	t_{su}	5.0	100	45	—	ns
Address to Write Disable		10	80	30	—	
		15	40	10	—	
Removal Time	t_{rem}	5.0	0	– 80	—	ns
Write Disable to Address		10	0	– 40	—	
		15	0	– 40	—	

* The formulas given are for the typical characteristics only at 25°C.
#Data labelled “Typ” is not to be used for design purposes but is intended as an indication of the IC’s potential performance.

MC14099B
FUNCTION DIAGRAM



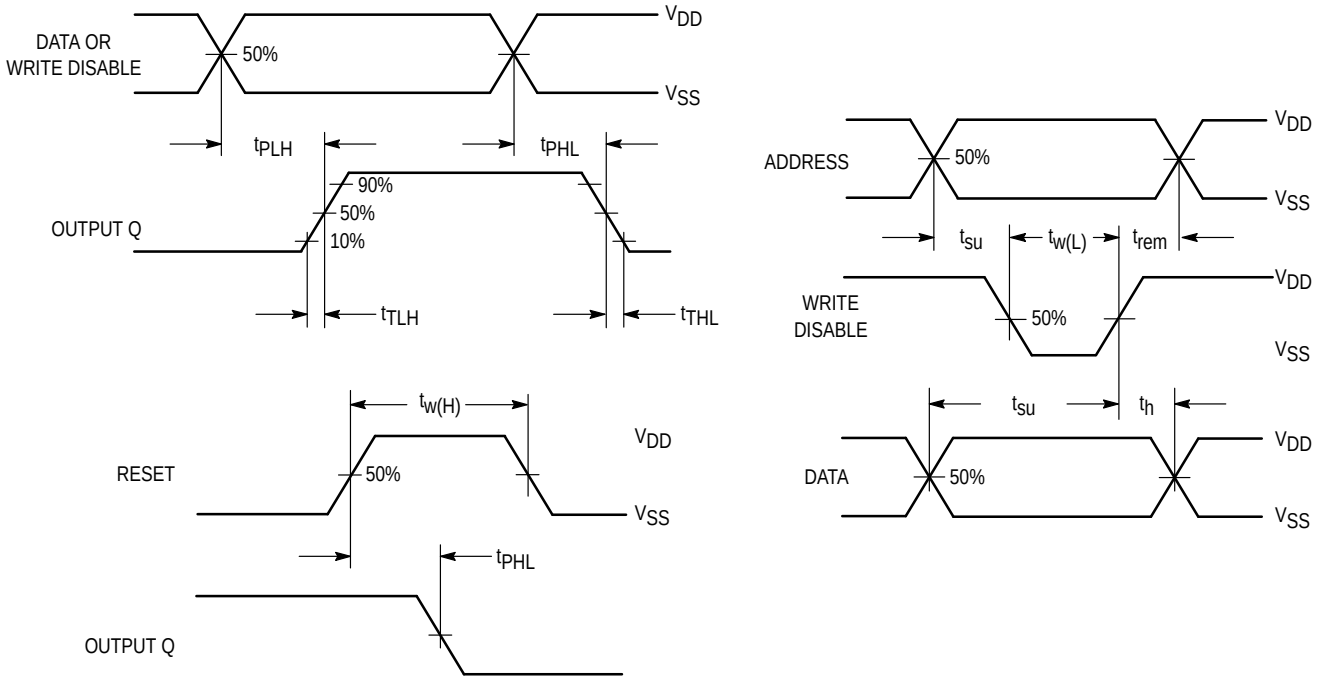
TRUTH TABLE

Write Disable	Reset	Addressed Latch	Unaddressed Latches
0	0	Data	Q_n*
0	1	Data	Reset†
1	0	Q_n*	Q_n*
1	1	Reset	Reset

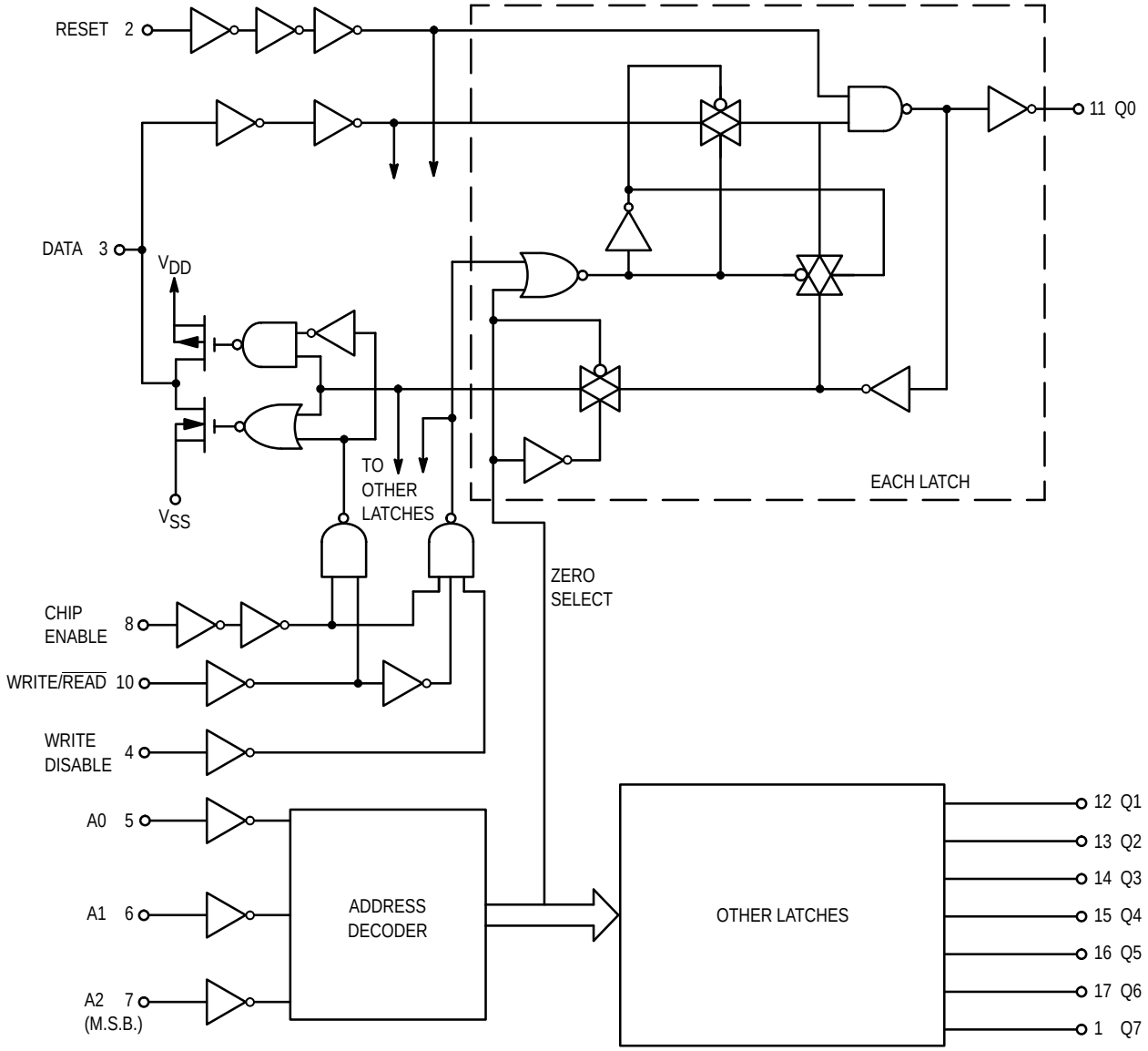
* Q_n is previous state of latch.
†Reset to zero state.

CAUTION: To avoid unintentional data changes in the latches, Write Disable must be active (high) during transitions on the address inputs A0, A1, and A2.

SWITCHING WAVEFORMS



MC14599B
FUNCTION DIAGRAM



TRUTH TABLE

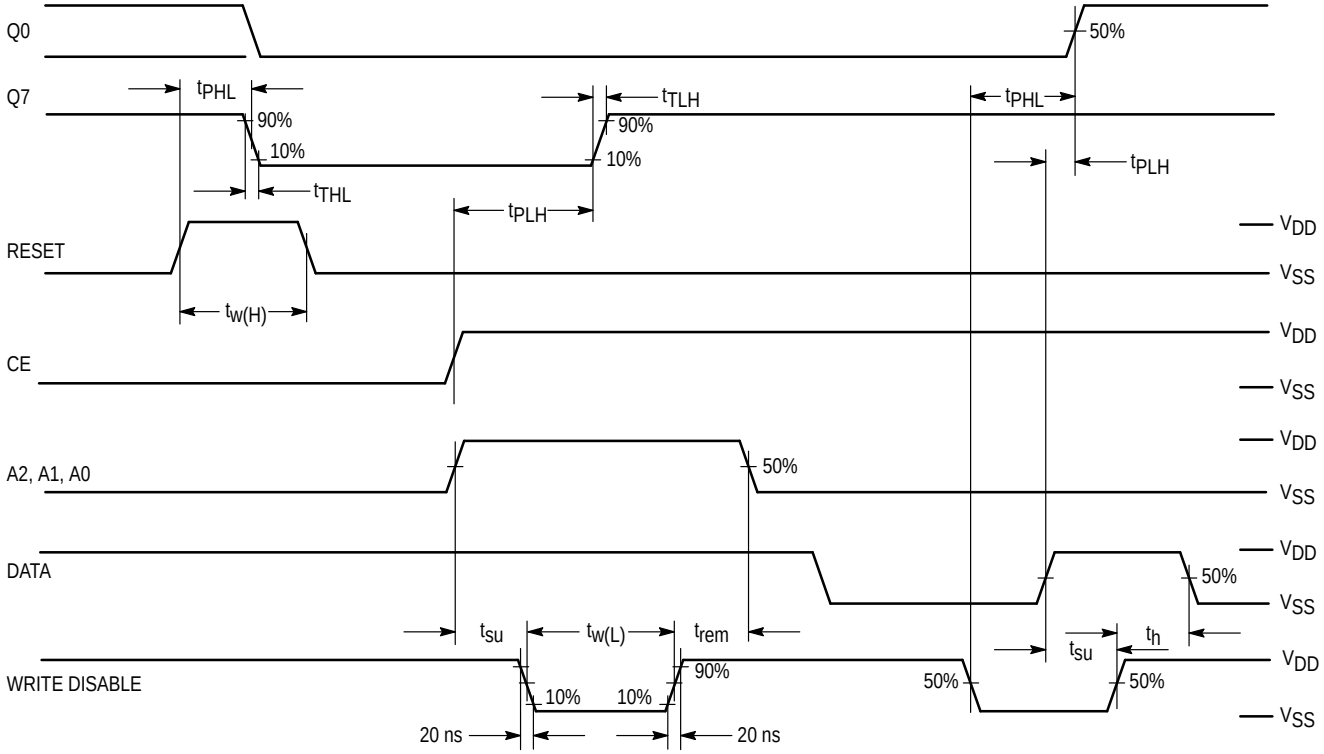
Chip Enable	Write/$\overline{Read}$	Write Disable	Reset	Addressed Latch	Other Latches	Data Pin
0	X	X	0	*	*	Z
1	1	0	0	Data	*	Input
1	1	1	0	*	*	Z
1	0	X	0	*	*	Q_n
X	X	X	1	0	0	Z/0

X = Don't care.
* = No change in state of latch.
Z = High impedance.
Q_n = State of addressed latch.

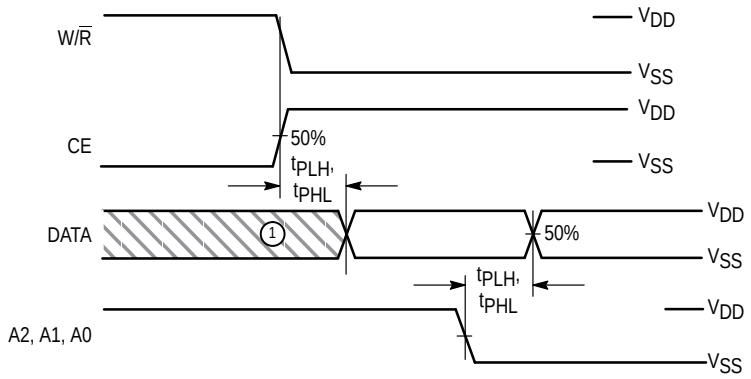
CAUTION: To avoid unintentional data changes in the latches, Write Disable must be active (high) during transitions on the address inputs A0, A1, and A2.

MC14599B
SWITCHING WAVEFORMS

DATA WRITE



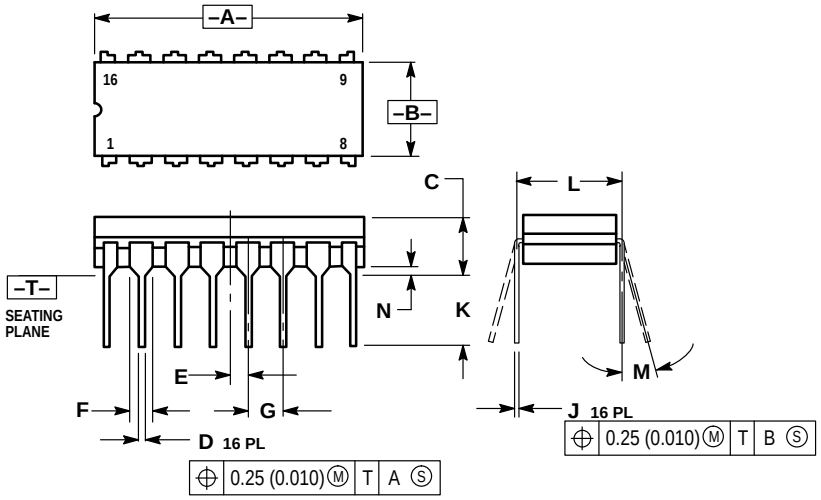
DATA READ



NOTE: 1. Invalid Data Output
2. Reset in LOW State

OUTLINE DIMENSIONS

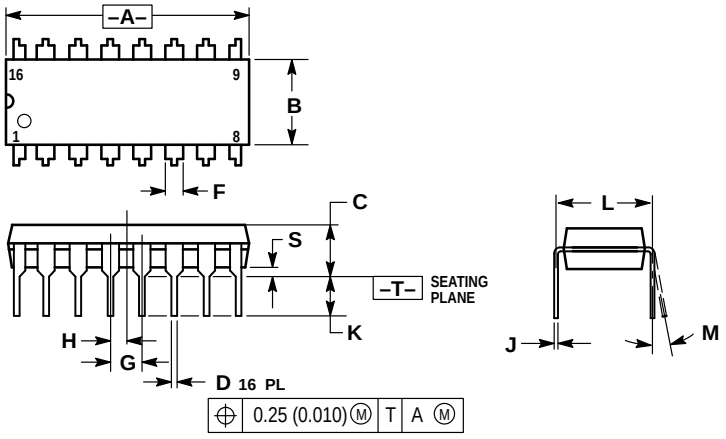
L SUFFIX
CERAMIC DIP PACKAGE
CASE 620–10
ISSUE V



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
4. DIMENSION F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC BODY.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.750	0.785	19.05	19.93
B	0.240	0.295	6.10	7.49
C	—	0.200	—	5.08
D	0.015	0.020	0.39	0.50
E	0.050 BSC		1.27 BSC	
F	0.055	0.065	1.40	1.65
G	0.100 BSC		2.54 BSC	
H	0.008	0.015	0.21	0.38
K	0.125	0.170	3.18	4.31
L	0.300 BSC		7.62 BSC	
M	0 °	15 °	0 °	15 °
N	0.020	0.040	0.51	1.01

P SUFFIX
PLASTIC DIP PACKAGE
CASE 648–08
ISSUE R

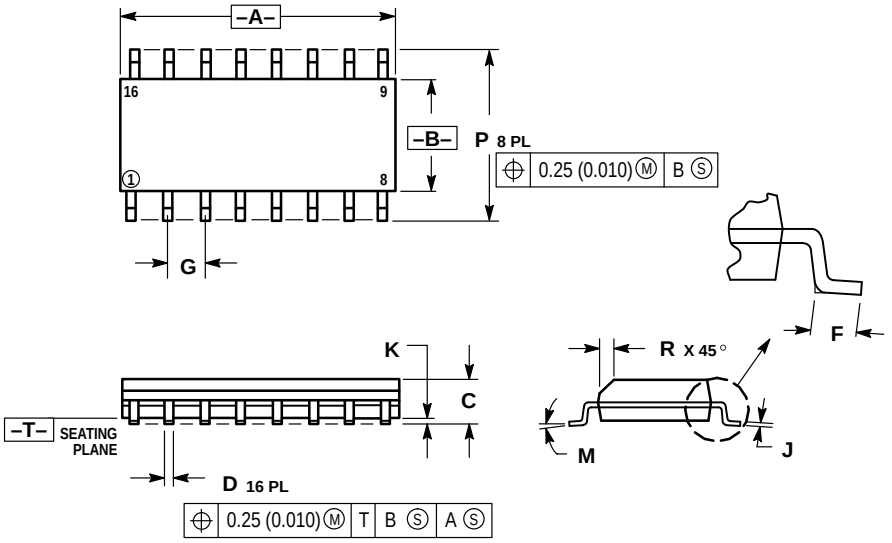


NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.740	0.770	18.80	19.55
B	0.250	0.270	6.35	6.85
C	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.040	0.70	1.02	1.77
G	0.100 BSC		2.54 BSC	
H	0.050 BSC		1.27 BSC	
J	0.008	0.015	0.21	0.38
K	0.110	0.130	2.80	3.30
L	0.295	0.305	7.50	7.74
M	0 °	10 °	0 °	10 °
S	0.020	0.040	0.51	1.01

OUTLINE DIMENSIONS

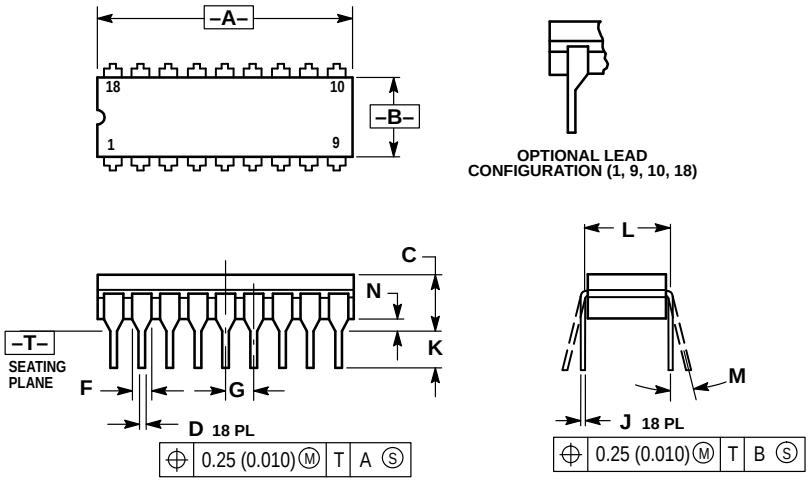
D SUFFIX
PLASTIC SOIC PACKAGE
CASE 751B–05
ISSUE J



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	9.80	10.00	0.386	0.393
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

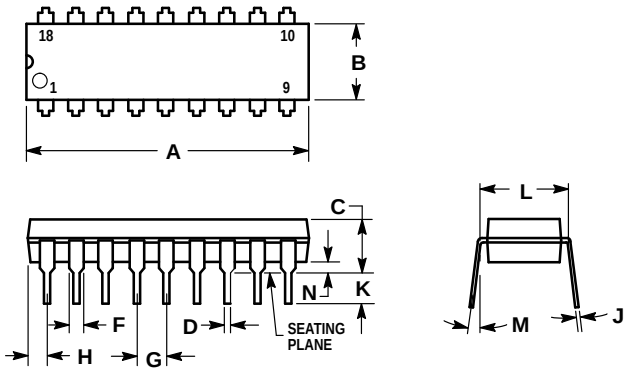
L SUFFIX
CERAMIC DIP PACKAGE
CASE 726–04
ISSUE G



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
4. DIMENSION F FOR FULL LEADS. HALF LEADS OPTIONAL AT LEAD POSITIONS 1, 9, 10, AND 18.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.880	0.910	22.35	23.11
B	0.240	0.295	6.10	7.49
C	—	0.200	—	5.08
D	0.015	0.021	0.38	0.53
F	0.055	0.070	1.40	1.78
G	0.100 BSC		2.54 BSC	
J	0.008	0.012	0.20	0.30
K	0.125	0.170	3.18	4.32
L	0.300 BSC		7.62 BSC	
M	0°	15°	0°	15°
N	0.020	0.040	0.51	1.02

P SUFFIX
PLASTIC DIP PACKAGE
CASE 707–02
ISSUE C



NOTES:
1. POSITIONAL TOLERANCE OF LEADS (D), SHALL BE WITHIN 0.25 (0.010) AT MAXIMUM MATERIAL CONDITION, IN RELATION TO SEATING PLANE AND EACH OTHER.
2. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
3. DIMENSION B DOES NOT INCLUDE MOLD FLASH.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	22.22	23.24	0.875	0.915
B	6.10	6.60	0.240	0.260
C	3.56	4.57	0.140	0.180
D	0.36	0.56	0.014	0.022
F	1.27	1.78	0.050	0.070
G	2.54 BSC		0.100 BSC	
H	1.02	1.52	0.040	0.060
J	0.20	0.30	0.008	0.012
K	2.92	3.43	0.115	0.135
L	7.62 BSC		0.300 BSC	
M	0 °	15 °	0 °	15 °
N	0.51	1.02	0.020	0.040

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